

DESCRIPTION

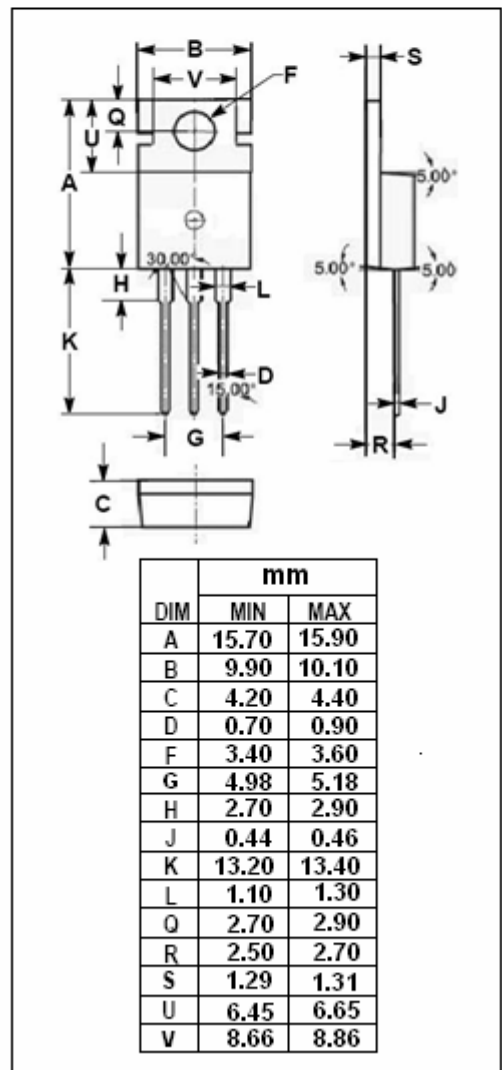
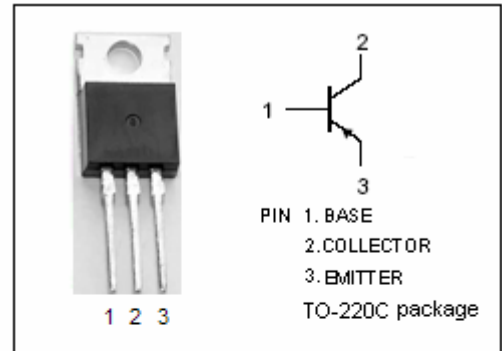
- DC Current Gain $-h_{FE} = 30(\text{Min})@ I_C = -0.3\text{A}$
- Collector-Emitter Sustaining Voltage-
: $V_{CEO(\text{SUS})} = -40\text{V}(\text{Min})$ - TIP42; $-60\text{V}(\text{Min})$ - TIP42A
-80V(Min)- TIP42B; $-100\text{V}(\text{Min})$ - TIP42C
- Complement to Type TIP41/41A/41B/41C

APPLICATIONS

- Designed for use in general purpose amplifier and switching applications

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	TIP42	-40
		TIP42A	-60
		TIP42B	-80
		TIP42C	-100
V_{CEO}	Collector-Emitter Voltage	TIP42	-40
		TIP42A	-60
		TIP42B	-80
		TIP42C	-100
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current-Continuous	-6	A
I_{CM}	Collector Current-Peak	-10	A
I_B	Base Current	-2	A
P_C	Collector Power Dissipation $T_C=25^\circ\text{C}$	65	W
	Collector Power Dissipation $T_a=25^\circ\text{C}$	2	
T_j	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-65~150	$^\circ\text{C}$



isc Silicon PNP Power Transistors

TIP42/42A/42B/42C

ELECTRICAL CHARACTERISTICS

 $T_C=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER		CONDITIONS	MIN	MAX	UNIT
$V_{CE(SUS)}$	Collector-Emitter Sustaining Voltage	TIP42	$I_C = -30\text{mA}; I_B = 0$	-40		V
		TIP42A		-60		
		TIP42B		-80		
		TIP42C		-100		
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage		$I_C = -6\text{A}; I_B = -0.6\text{A}$		-1.5	V
$V_{BE(on)}$	Base-Emitter On Voltage		$I_C = -6\text{A}; V_{CE} = -4\text{V}$		-2.0	V
I_{CES}	Collector Cutoff Current	TIP42	$V_{CE} = -40\text{V}; V_{EB} = 0$		-0.4	mA
		TIP42A	$V_{CE} = -60\text{V}; V_{EB} = 0$			
		TIP42B	$V_{CE} = -80\text{V}; V_{EB} = 0$			
		TIP42C	$V_{CE} = -100\text{V}; V_{EB} = 0$			
I_{CEO}	Collector Cutoff Current	TIP42/42A	$V_{CE} = -30\text{V}; I_B = 0$		-0.7	mA
		TIP42B/42C	$V_{CE} = -60\text{V}; I_B = 0$			
I_{EBO}	Emitter Cutoff Current		$V_{EB} = -5\text{V}; I_C = 0$		-1.0	mA
h_{FE-1}	DC Current Gain		$I_C = -0.3\text{A}; V_{CE} = -4\text{V}$	30		
h_{FE-2}	DC Current Gain		$I_C = -3\text{A}; V_{CE} = -4\text{V}$	15	75	
f_T	Current-Gain—Bandwidth Product		$I_C = -0.5\text{A}; V_{CE} = -10\text{V}$	3		MHz

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TIP42/42A/42B/42C

